

GS2515 Series

40V Low-Power LDO Regulator

General Description

The GS2515 is a 40V low-power high accuracy LDO regulator. The 2.5 μ A power consumption makes it ideal for most HV power-saving systems. The maximum operating voltage can be as high as 40V. The output accuracy is as excellent as $\pm 1.0\%$.

The other features include low dropout voltage, current limiting protection and thermal shutdown protection.

The GS2515 is available in SOT-23-3L, SOT-23-5L packages.

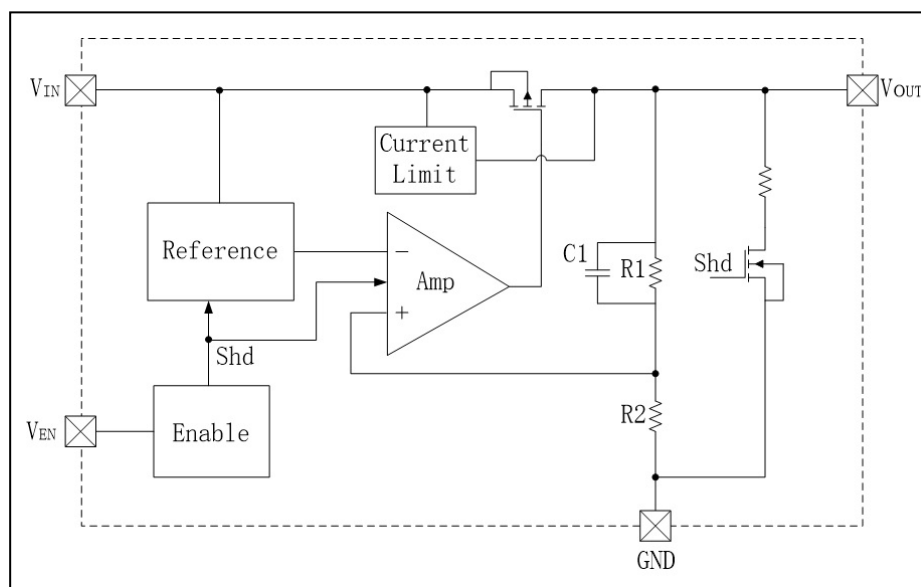
Features

- Maximum Operating Voltage: 40V
- Output Voltage: 1.8V ~ 5.0V
- Output Accuracy: $\pm 1.0\%$
- Low Power Consumption: 2.5 μ A
- <0.2 μ A Standby Current
- Current Limiting, Thermal Shutdown
- Available in SOT-23-3L, SOT-23-5L Packages

Applications

- Battery Supplied Systems
- Telecom Systems
- Audio & Video Devices

Function Block Diagram



Packages & Pin Assignments

SOT-23-3L		SOT-23-5L	
Pin Name	Function		
GND	Ground Pin		
V _{OUT}	Output		
V _{IN}	Power Supply Input		
EN	Chip Enable		
NC	Not Connect		

Ordering and Marking Information

Ordering Information			
SOT-23-3L	SOT-23-5L	Marking	Output Voltage
GS2515JL18F	GS2515L18F	LW6518 □□□□	1.8V
GS2515JL25F	GS2515L25F	LW6525 □□□□	2.5V
GS2515JL30F	GS2515L30F	LW6530 □□□□	3.0V
GS2515JL33F	GS2515L33F	LW6533 □□□□	3.3V
GS2515JL36F	GS2515L36F	LW6536 □□□□	3.6V
GS2515JL40F	GS2515L40F	LW6540 □□□□	4.0V
GS2515JL42F	GS2515L42F	LW6542 □□□□	4.2V
GS2515JL50F	GS2515L50F	LW6550 □□□□	5.0V

GS2515¹²³⁴⁵

Product Code:

GS2515

Package Code:

- ¹ ² is JL and L
 - JL is SOT-23-3L
 - L is SOT-23-5L

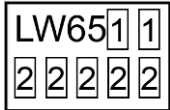
Voltage Code:

- ³ ⁴ is 18, 25, 30 and so on.
 - 18 for 1.8V, 25 for 2.5V, 30 for 3.0V and so on.

Green Level:

⁵ is F stands for RoHS Compliant and Halogen Free

Marking Information



Product Code:

- LW65

Voltage Code:

- 11 is 18, 25, 30 and so on.
- 18 for 1.8V
 - 25 for 2.5V
 - 30 for 3.0V
 - 33 for 3.3V
 - 36 for 3.6V
 - 40 for 4.0V
 - 42 for 4.2V
 - 50 for 5.0V

GS Code:

22222 is GS Code

Absolute Maximum Ratings ¹

T_A=25°C, unless otherwise specified

Symbol	Parameter	Rating	Units	
V _{IN}	Supply Voltage	-0.3~44	V	
V _{EN}	EN pin to GND Voltage	-0.3~44	V	
V _{OUT}	V _{OUT} pin to GND Voltage	-0.3~6.0	V	
PD	Maximum Power Dissipation ²	SOT-23-3L	0.5	W
		SOT-23-5L		
R _{θJA}	Thermal Resistance, Junction to Ambient ²	SOT-23-3L	250	°C/W
		SOT-23-5L		
T _J	Operating Junction Temperature	-40 ~ 150	°C	
T _{STG}	Storage Temperature Range	-40 ~ 150	°C	
T _{LEAD}	Lead Temperature (Soldering 10sec)	260	°C	

Note:

1. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. Device mounted on FR-4 PCB.

Recommended Operating Range

Symbol	Parameter	Value	Units
V _{IN}	V _{IN} Supply Voltage	2.5 ~ 40	V
V _{EN}	EN Pin Voltage	0 ~ 40	V
V _{OUT}	V _{OUT} Pin Voltage	1.5 ~ 5.0	V
I _{OUT}	Output Current	0 ~ 150	mA
T _J	Junction Temperature Range	-40 ~ 125	°C

Electrical Characteristics

V_{IN}=V_{OUT}+1V, V_{OUT}=3.3V, C_{IN}=C_{OUT}=1uF, T_A =25°C, unless otherwise specified.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units	
V _{IN}	Input Voltage	-	2.5	-	40	V	
V _{OUT}	Output Accuracy	I _{OUT} = 1mA	-1.0	-	+1.0	%	
I _{LIM}	Current Limit	V _{IN} =4.3V, V _{OUT} =3.3V	150	210	-	mA	
I _Q	Quiescent Current	V _{IN} =V _{EN} =V _{OUT} +1V, No Load					
		V _{OUT} <1.8V	-	3.0	4.0	μA	
		V _{OUT} ≥1.8V	-	2.5	3.5	μA	
I _{SHD}	Shutdown Current	V _{IN} =12V, V _{EN} =0V	-	0.1	0.2	μA	
V _{DROP}	Dropout Voltage ³	I _{OUT} =100mA, V _{OUT} =1.8V	-	700	-	mV	
		I _{OUT} =100mA, V _{OUT} =3.3V	-	450	-		
		I _{OUT} =100mA, V _{OUT} =5.0V	-	360	-		
S _{LINE}	Line Regulation	V _{IN} = V _{OUT} +1V to 40V, I _{OUT} =1mA	-	0.02	0.05	%/V	
S _{LOAD}	Load Regulation	1mA ≤ I _{OUT} ≤ 150mA	-	0.005	0.01	%/mA	
I _{SHORT}	Short Current	V _{OUT} =0V	-	15	-	mA	
V _{ENH}	EN High Voltage	V _{IN} =2.5V to 40V, I _{OUT} =1mA	1.5	-	-	V	
V _{ENL}	EN Low Voltage		-	-	0.5	V	
PSRR	Power Supply Rejection Ratio	V _{IN} =5.0V, C _{IN} =None, I _{OUT} =10mA	f=217Hz	-	86	-	dB
			f=1KHz	-	81	-	
			f=10KHz	-	64	-	
			f=100KHz	-	40	-	
T _{SD}	Overheat Protection	Temperature rising	-	165	-	°C	
ΔT _{SD}	TSD Hysteresis	Temperature falling	-	15	-	°C	
R _{DSCHG}	R _{ON} of V _{OUT} Discharge MOSFET	V _{IN} =12V, V _{OUT} =5.0V, V _{EN} =0V	-	130	-	Ω	

Note:

3. The dropout voltage is defined as V_{IN} - V_{OUT}, when V_{OUT} =95% x V_{OUT(NOM)}

Typical Performance Characteristics

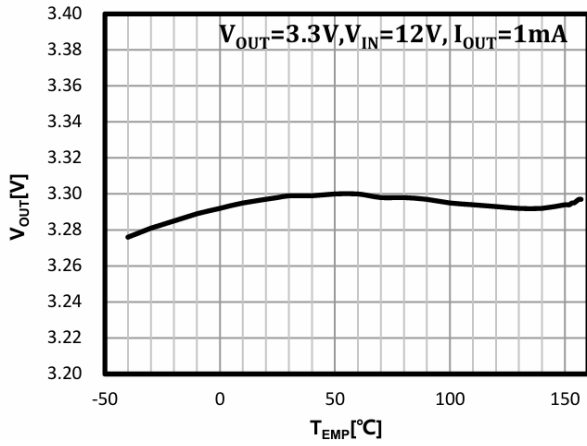


Figure 1. V_{OUT} vs Temperature

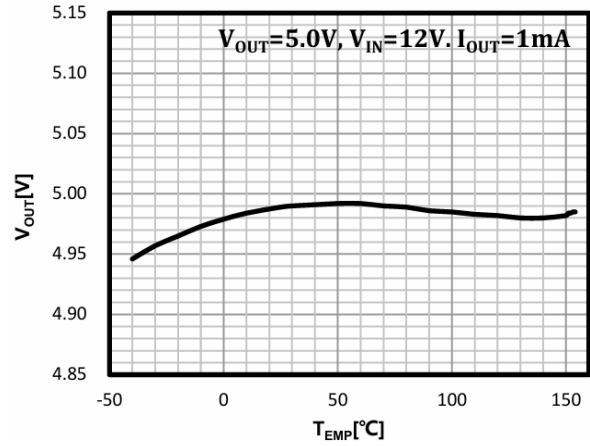


Figure 2. V_{OUT} vs Temperature

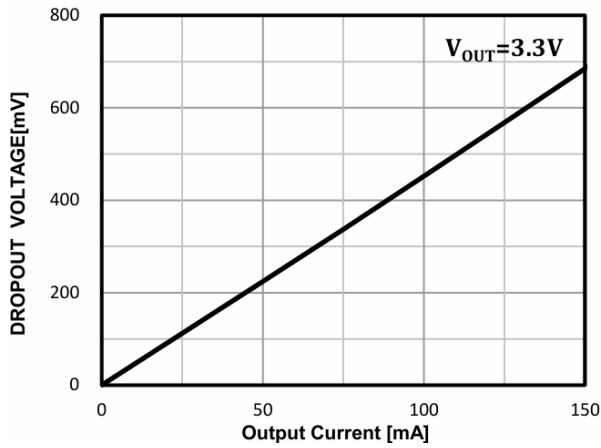


Figure 3. Dropout Voltage vs Output Current

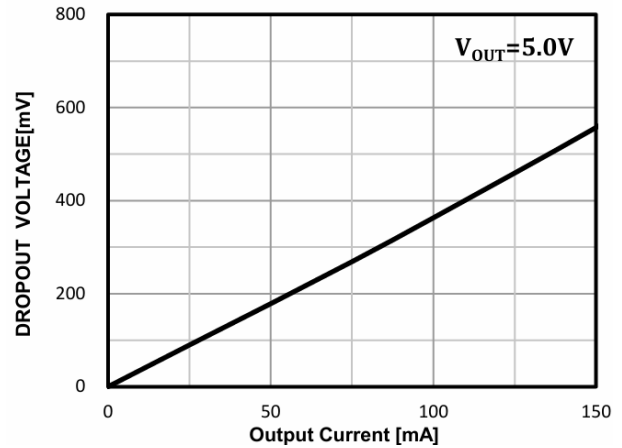


Figure 4. Dropout Voltage vs Output Current

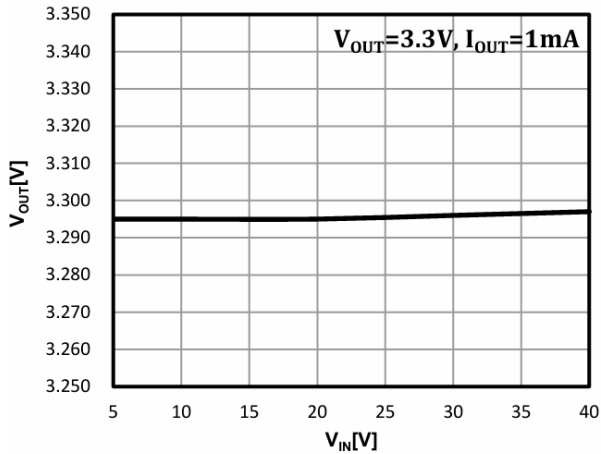


Figure 5. Line Regulation vs V_{IN}

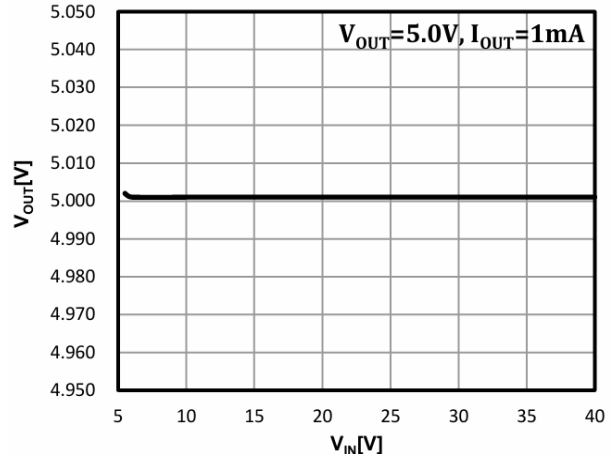


Figure 6. Line Regulation vs V_{IN}

Typical Performance Characteristics

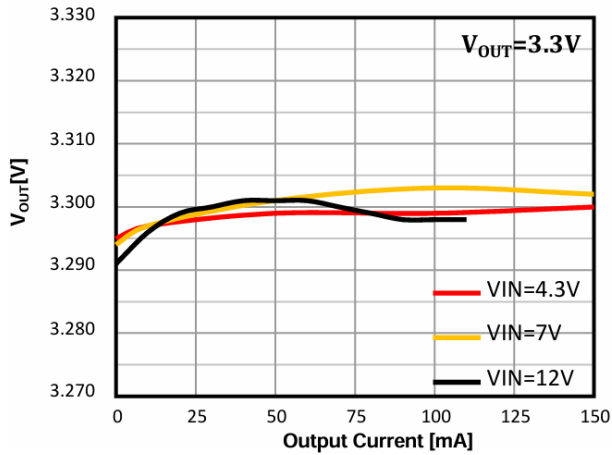


Figure 7. Load Regulation vs Output Current

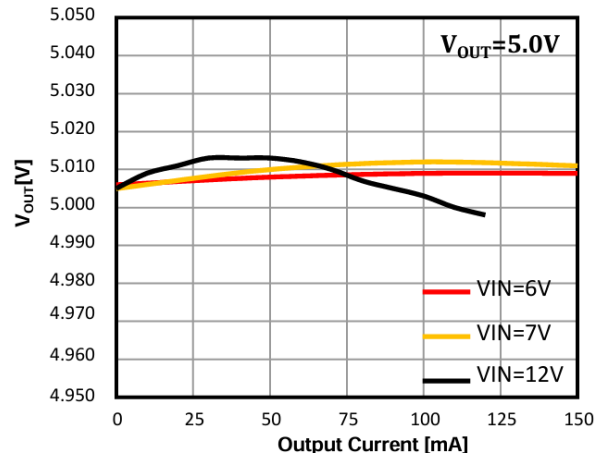
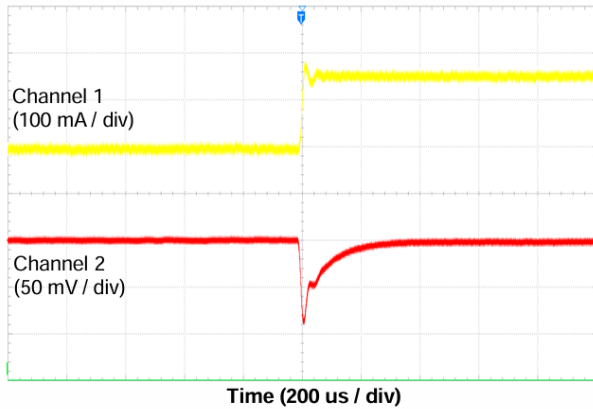
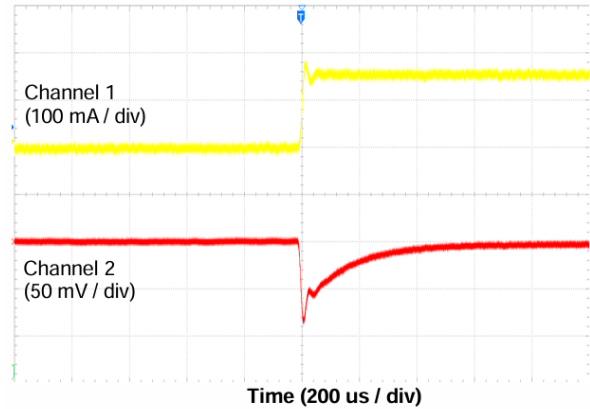


Figure 8. Load Regulation vs Output Current



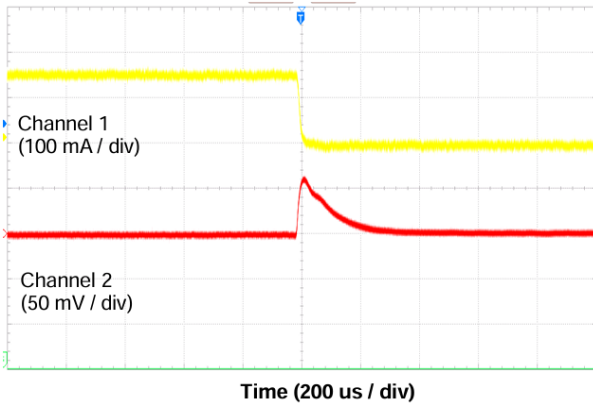
Channel 1 = I_{OUT} , channel 2 = V_{OUT} , $V_{IN}=4.3V$, $V_{OUT}=3.3V$

Figure 9. Load Transient (1 mA to 150 mA)



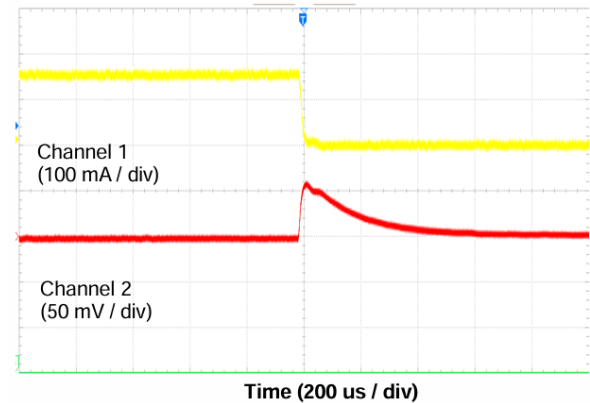
Channel 1 = I_{OUT} , channel 2 = V_{OUT} , $V_{IN}=6.0V$, $V_{OUT}=5.0V$

Figure 10. Load Transient (1 mA to 150 mA)



Channel 1 = I_{OUT} , channel 2 = V_{OUT} , $V_{IN}=4.3V$, $V_{OUT}=3.3V$

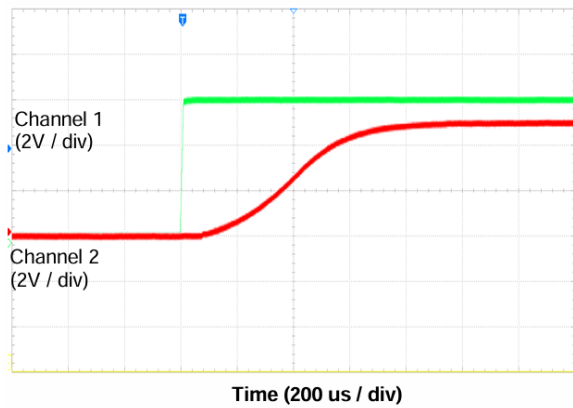
Figure 11. Load Transient (150 mA to 1 mA)



Channel 1 = I_{OUT} , channel 2 = V_{OUT} , $V_{IN}=6.0V$, $V_{OUT}=5.0V$

Figure 12. Load Transient (150 mA to 1 mA)

Typical Performance Characteristics



Channel 1 = En, channel 2 = V_{OUT} , $V_{IN}=6.0V$, $V_{OUT}=5.0V$, $I_{OUT}=10mA$

Figure 13. Power-Up with Enable

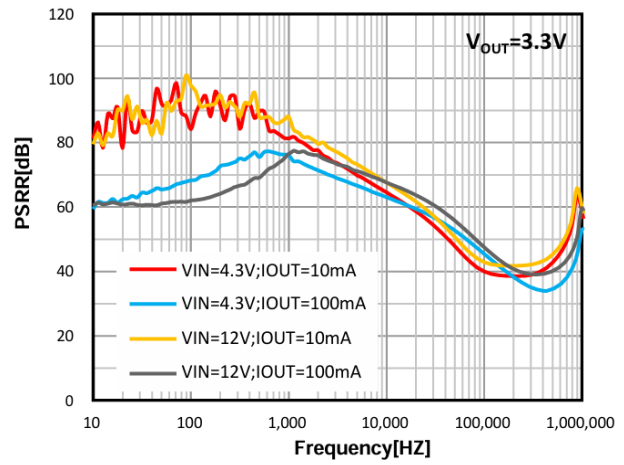
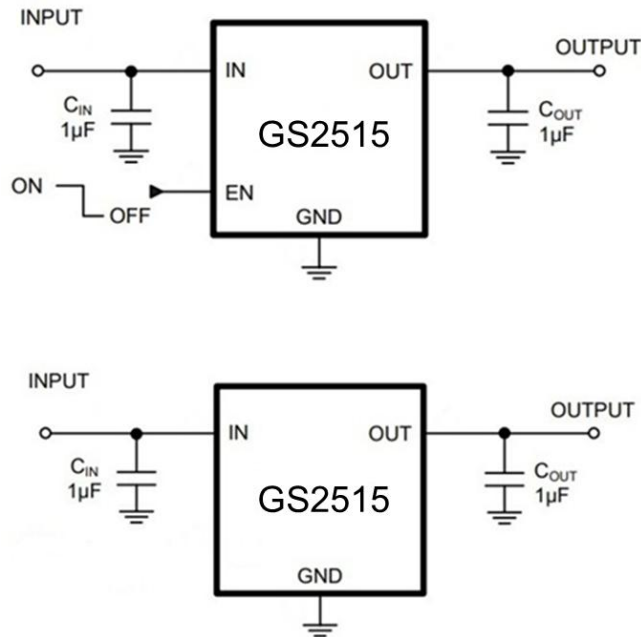


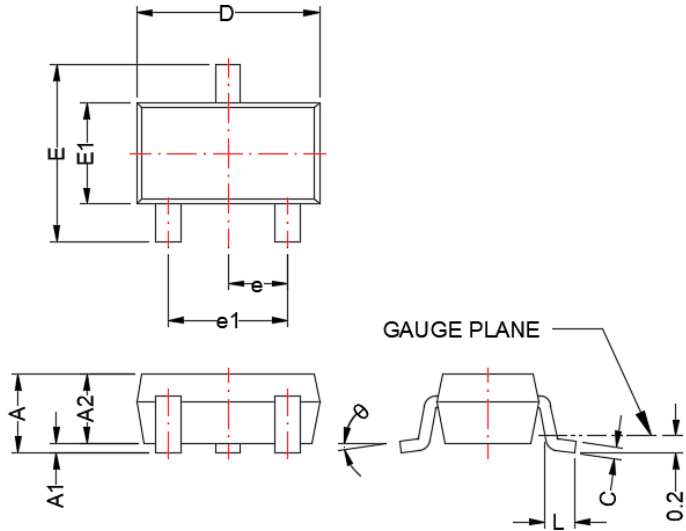
Figure 14. PSRR vs Frequency

Typical Application Circuit

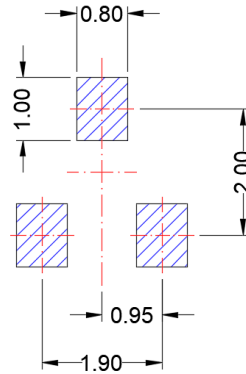


SOT-23-3L

Package Dimension



Recommended Land Pattern



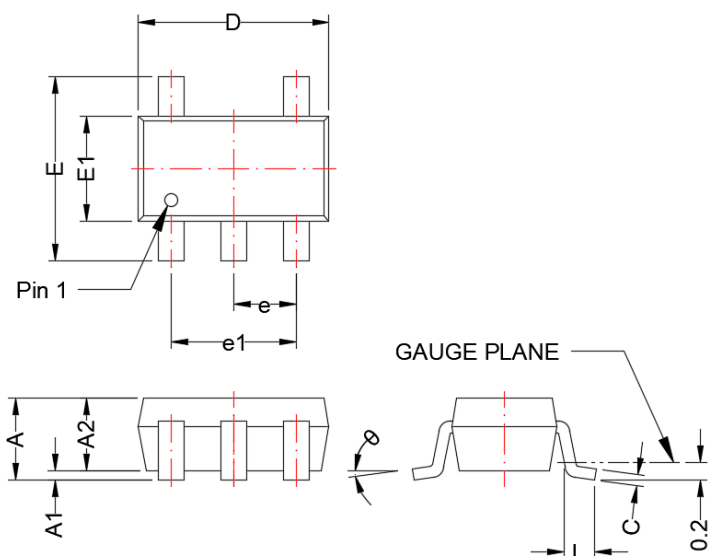
Dimensions

Symbol	Millimeters		Inches	
	MIN	MAX	Min	MIN
A	0.90	1.45	0.035	0.057
A1	0.00	0.15	0.000	0.006
A2	0.90	1.30	0.035	0.051
b	0.30	0.50	0.012	0.020
c	0.08	0.26	0.003	0.010
D	2.70	3.10	0.106	0.122
E	2.20	3.00	0.087	0.118
E1	1.30	1.75	0.051	0.069
e	0.95 BSC		0.037 BSC	
e1	1.90 BSC		0.075 BSC	
L	0.3	0.6	0.012	0.024
θ	0°	8°	0°	8°

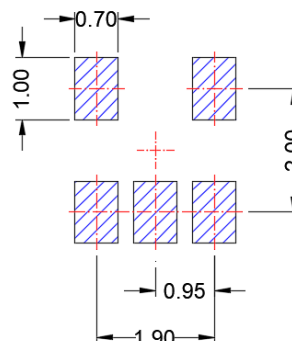
Note:
Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.

SOT-23-5L

Package Dimension



Recommended Land Pattern



Dimensions





Symbol	Millimeters		Inches	
	MIN	MAX	Min	MIN
A	0.90	1.45	0.035	0.057
A1	0.00	0.15	0.000	0.006
A2	0.90	1.30	0.035	0.051
b	0.30	0.50	0.012	0.020
c	0.08	0.26	0.003	0.010
D	2.70	3.10	0.106	0.122
E	2.20	3.00	0.087	0.118
E1	1.30	1.75	0.051	0.069
e	0.95 BSC		0.037 BSC	
e1	1.90 BSC		0.075 BSC	
L	0.3	0.6	0.012	0.024
θ	0°	8°	0°	8°



Note:
Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.

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